

AMENDMENTS TO THE CLAIMS

The following is a complete, marked up listing of revised claims with a status identifier in parentheses, underlined text indicating insertions, and strikethrough and/or double-bracketed text indicating deletions.

Listing of the Claims

1. (Original) A method for improving the luminescent efficiency of semiconductor nanocrystals which comprises surface-treating the semiconductor nanocrystals with a reducing agent.
2. (Original) The method of claim 1, wherein the semiconductor nanocrystals are synthesized by a wet chemistry method.
3. (Currently Amended) The method according to claim 1, wherein the semiconductor nanocrystals are core-shell, alloy or gradient structures made of at least one material selected from the group consisting of CdS, CdSe~~CdSe~~, CdTe, ,ZnS, ZnSe, ZnTe, HgS, HgSe, HgTe, GaN, GaP, GaAs, InP and InAs.
4. (Currently Amended) The method according to claim 1, wherein the reducing agent is a hydride ion-generating salt, an organic reducing agent, a reducing gas or solution containing the gas, ~~such as~~
sodium borohydride, lithium borohydride, lithium aluminum hydride, hydrazine, ~~hydrogen gas, hydrogen sulfide or and ammonia.~~

5. (Currently Amended) The method according to claim 1, wherein the surface of the nanocrystals is reduced or oxidized to in a state where the nanocrystals are coordinated by an organic dispersant and further comprising dispersing the nanocrystals in a solvent having an affinity with the dispersant.
6. (Currently Amended) The method according to claim ~~5~~4, wherein the dispersant is at least one compound selected from the group consisting of C₂-18 alkylcarboxylic acids, C₂-18 alkenylcarboxylic acids, C₂-18 alkylsulfonic acids, C₂-18 alkenylsulfonic acids, C₂-18 phosphonic acids, C₂-18 alkylamines, C₂-18 alkenylamines and the salts thereof.
7. (Currently Amended) The method according to claim ~~6~~5, wherein the dispersant is at least one compound selected from the group consisting of oleic acid, stearic acid, palmitic acid, hexylphosphonic acid, n-octylphosphonic acid, tetradecylphosphonic acid, octadecylphosphonic acid, n-octyl amine and hexadecyl amine.
8. (Original) The method according to claim 1, wherein the nanocrystals and the reducing agent are mixed in a weight ratio of 1:10-10:1.
9. (Original) The method according to claim 1, wherein the surface treatment of the nanocrystals is carried out in the range of 0-100°C.
10. (Original) The method according to claim 1, wherein the surface treatment of the nanocrystals is carried out for 1 second to 2 days.

11. (Original) The method according to claim 1, wherein the nanocrystals have a shape or mixed shape of a sphere, a rod, a tripod, a tetrapod, a cube, a box or a star.
12. (Original) The method according to claim 1, wherein the nanocrystals have sizes of 1-50nm.
13. (Original) A semiconductor nanocrystal prepared by the method of claim 1.
14. (Currently Amended) An organic electroluminescent device comprising a plurality of organic and inorganic layers including a luminescent layer, wherein the luminescent layer comprises the semiconductor nanocrystals of claim ~~13~~12.
15. (Original) A semiconductor nanocrystal having a chemically reduced or oxidized surface.
16. (New) The method according to claim 4, wherein the reducing agent is selected from a group consisting of sodium borohydride, lithium borohydride, lithium aluminum hydride, hydrazine, hydrogen gas, hydrogen sulfide or ammonia.